

Examples of the claim correspondence

The claims in the following cases are considered to “sufficiently correspond”.

Example 1

<i>US claims</i>	<i>CZ claims</i>	<i>Comment</i>
<i>1</i>	<i>1</i>	<i>The CZ claim contains an additional component compared to the US granted claim.</i>

Patentable claim according to the USPTO	CZ claim
<p>A system for presenting a container storing at least one article to a processing tool, comprising:</p> <p>(a) a load port, including: a frame having an opening; a support structure being adapted to receive a container, and a drive mechanism for moving said support structure substantially vertically between a first height and a second height; and</p> <p>(b) a conveyor for movably supporting the container substantially along a container transport plane; wherein a container traveling on said conveyor moves unobstructed over said support structure when said support structure is located in said second height, wherein the container traveling unobstructed does not contact said support structure while traveling over said support structure located at said second height, wherein said support structure, when located at said second height, is located below said transport plane.</p>	<p>A system for presenting a container storing at least one article to a processing tool, comprising:</p> <p>(a) a load port, including: a frame having an opening; a support structure being adapted to receive a container, and a drive mechanism for moving said support structure substantially vertically between a first height and a second height; and</p> <p>(b) a conveyor for movably supporting the container substantially along a container transport plane; wherein a container traveling on said conveyor moves unobstructed over said support structure when said support structure is located in said second height, wherein the container traveling unobstructed does not contact said support structure while traveling over said support structure located at said second height, wherein said support structure, when located at said second height, is located below said transport plane, <u>wherein said support structure, when located at said first height, is located above said transport plane*</u>.</p>
<p>* These additional components are NOT included in the USPTO granted claim but they are included in the <u>description of the US application.</u></p>	

Example 2

<i>US claims</i>	<i>CZ claims</i>	<i>Comment</i>
<i>1</i>	<i>1</i>	<i>The same</i>
<i>none</i>	<i>2</i>	<i>CZ claim 2 is dependent on CZ claim 1, which has been granted by the USPTO.</i>

Patentable claim according to the USPTO	CZ claim
1. A nitride-based semiconductor device comprising: a first semiconductor layer, consisting of either an n-type nitride-based semiconductor layer having a wurtzite structure or an n-type nitride-based semiconductor substrate having a wurtzite structure; and an n-side electrode formed on a back surface of said first semiconductor layer, wherein a dislocation density is not more than $1 \cdot 10^9 \text{ cm}^{-2}$ in the vicinity of the interface between said first semiconductor layer and said n-side electrode, and contact resistance between said n-side electrode and said first semiconductor layer is not more than $0.05 \text{ } \Omega\text{cm}^2$.	1. (The same)
2. (None)	<i>2. The nitride-based semiconductor device according to claim 1, wherein said first semiconductor layer includes an n-type dopant.*</i>
<p><i>Comment: * This additional part (second claim) is NOT included in the USPTO granted claim but it is included in the description of the US application.</i></p>	